

## TC74HCU04AP, TC74HCU04AF, TC74HCU04AFN

### Hex Inverter

The TC74HCU04A is a high speed CMOS INVERTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

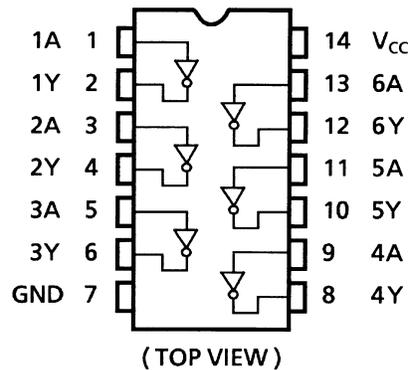
Since the internal circuit is composed of a single stage inverter, it can be used in analog applications such as crystal oscillators.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

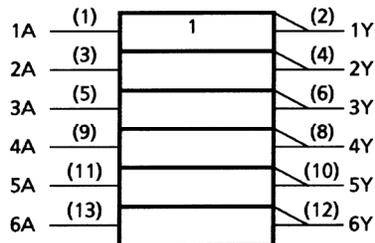
### Features

- High speed:  $t_{pd} = 4 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 1 \mu\text{A (max)}$  at  $T_a = 25^\circ\text{C}$
- High noise immunity:  $V_{NIH} = V_{NHL} = 10\% V_{CC} \text{ (min)}$
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC} \text{ (opr)} = 2 \text{ to } 6 \text{ V}$
- Pin and function compatible with 74LS04

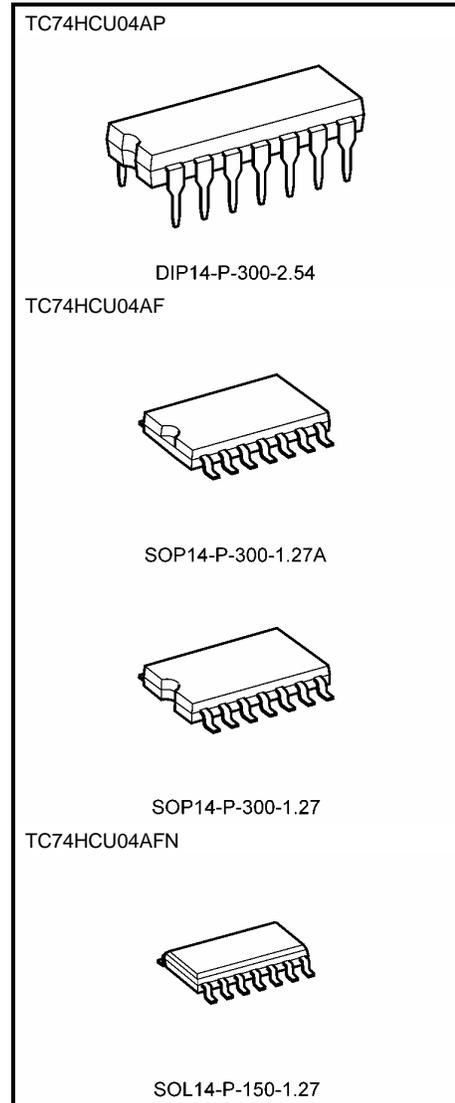
### Pin Assignment



### IEC Logic Symbol



Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight	
DIP14-P-300-2.54	: 0.96 g (typ.)
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)

## Truth Table

A	Y
L	H
H	L

## Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5 to 7	V
DC input voltage	$V_{IN}$	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$	$\pm 20$	mA
Output diode current	$I_{OK}$	$\pm 20$	mA
DC output current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 50$	mA
Power dissipation	$P_D$	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	$T_{stg}$	-65 to 150	$^{\circ}C$

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of  $T_a = -40$  to  $65^{\circ}C$ . From  $T_a = 65$  to  $85^{\circ}C$  a derating factor of  $-10$  mW/ $^{\circ}C$  shall be applied until 300 mW.

## Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	2 to 6	V
Input voltage	$V_{IN}$	0 to $V_{CC}$	V
Output voltage	$V_{OUT}$	0 to $V_{CC}$	V
Operating temperature	$T_{opr}$	-40 to 85	$^{\circ}C$

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## Electrical Characteristics

### DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V <sub>IH</sub>	—		2.0	1.7	—	—	1.7	—	V
				4.5	3.6	—	—	3.6	—	
				6.0	4.8	—	—	4.8	—	
Low-level input voltage	V <sub>IL</sub>	—		2.0	—	—	0.3	—	0.3	V
				4.5	—	—	0.9	—	0.9	
				6.0	—	—	1.2	—	1.2	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -20 μA	2.0	1.8	2.0	—	1.9	—	V
				4.5	4.0	4.5	—	4.0	—	
		V <sub>IN</sub> = GND	I <sub>OH</sub> = -4 mA I <sub>OH</sub> = -5.2 mA	4.5	4.18	4.31	—	4.13	—	
				6.0	5.68	5.80	—	5.63	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 20 μA	2.0	—	0.0	0.2	—	0.2	V
				4.5	—	0.0	0.5	—	0.5	
		V <sub>IN</sub> = V <sub>CC</sub>	I <sub>OL</sub> = 4 mA I <sub>OL</sub> = 5.2 mA	4.5	—	0.17	0.26	—	0.33	
				6.0	—	0.18	0.26	—	0.33	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	—	—	1.0	—	10.0	μA

### AC Characteristics (C<sub>L</sub> = 15 pF, V<sub>CC</sub> = 5 V, Ta = 25°C, input: t<sub>r</sub> = t<sub>f</sub> = 6 ns)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Output transition time	t <sub>TLH</sub>	—	—	4	8	ns
	t <sub>THL</sub>					
Propagation delay time	t <sub>pLH</sub>	—	—	4	8	ns
	t <sub>pHL</sub>					

## AC Characteristics (C<sub>L</sub> = 50 pF, input: t<sub>r</sub> = t<sub>f</sub> = 6 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C				Ta = -40 to 85°C		Unit
			V <sub>CC</sub> (V)	Min	Typ.	Max	Min	Max	
Output transition time	t <sub>TLH</sub>	—	2.0	—	30	75	—	95	ns
	t <sub>THL</sub>		4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation delay time	t <sub>pLH</sub>	—	2.0	—	18	60	—	75	ns
	t <sub>pHL</sub>		4.5	—	6	12	—	15	
			6.0	—	5	10	—	13	
Input capacitance	C <sub>IN</sub>	—	—	9	15	—	15	pF	
Power dissipation capacitance	C <sub>PD</sub> (Note)	—	—	13	—	—	—	pF	

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

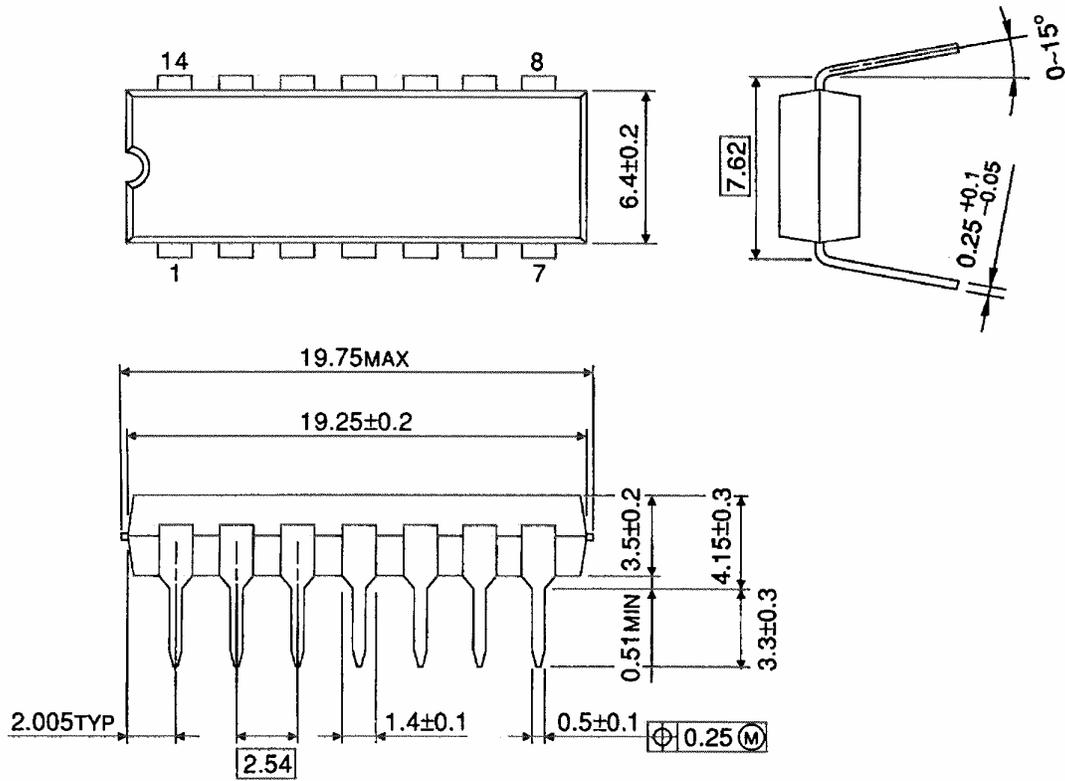
Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per gate)}$$

## Package Dimensions

DIP14-P-300-2.54

Unit : mm

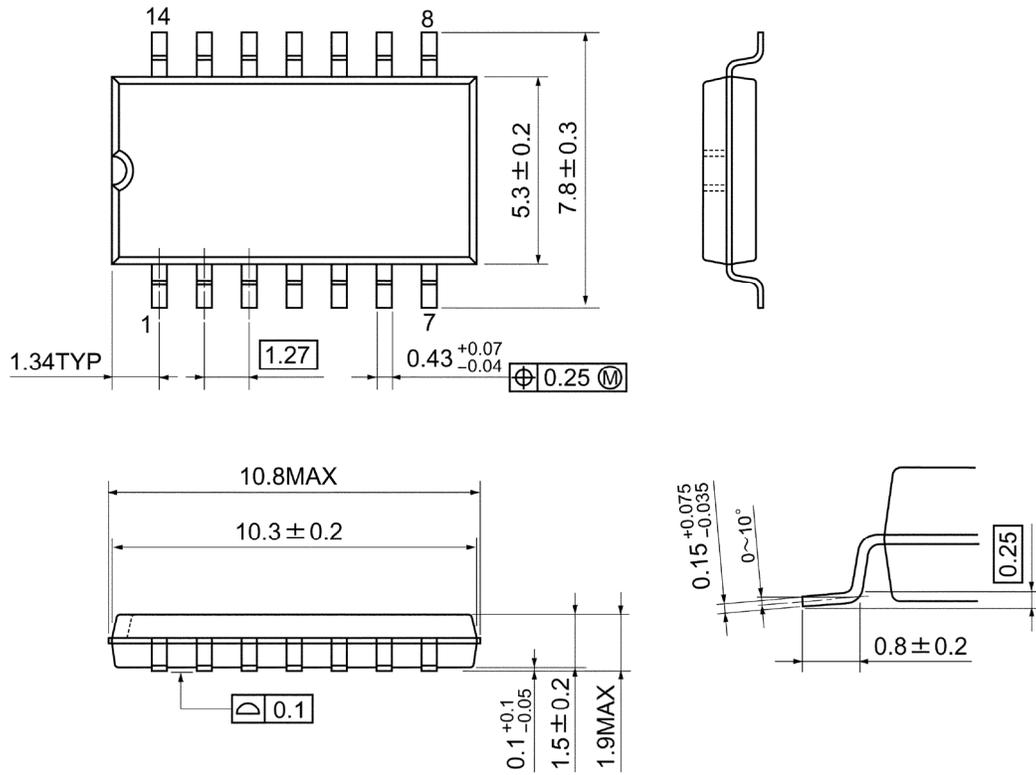


Weight: 0.96 g (typ.)

## Package Dimensions

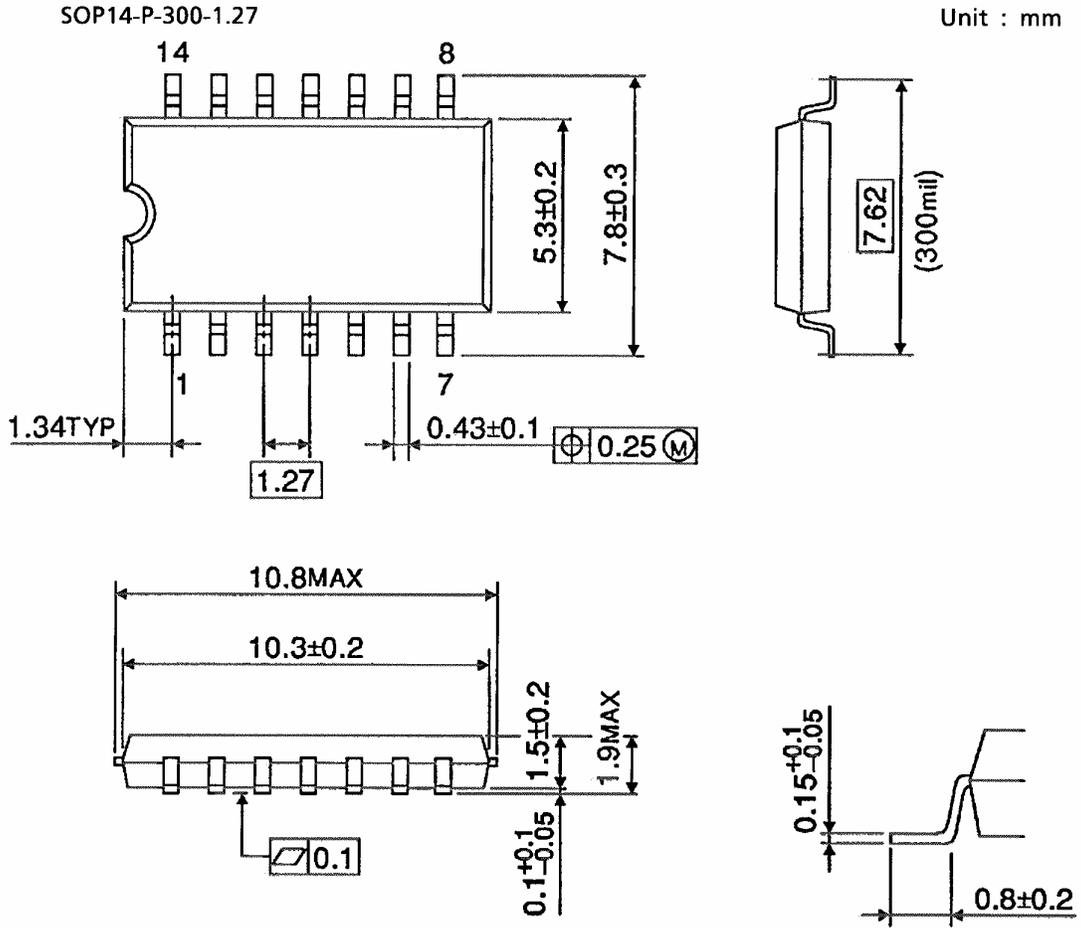
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

**Package Dimensions**

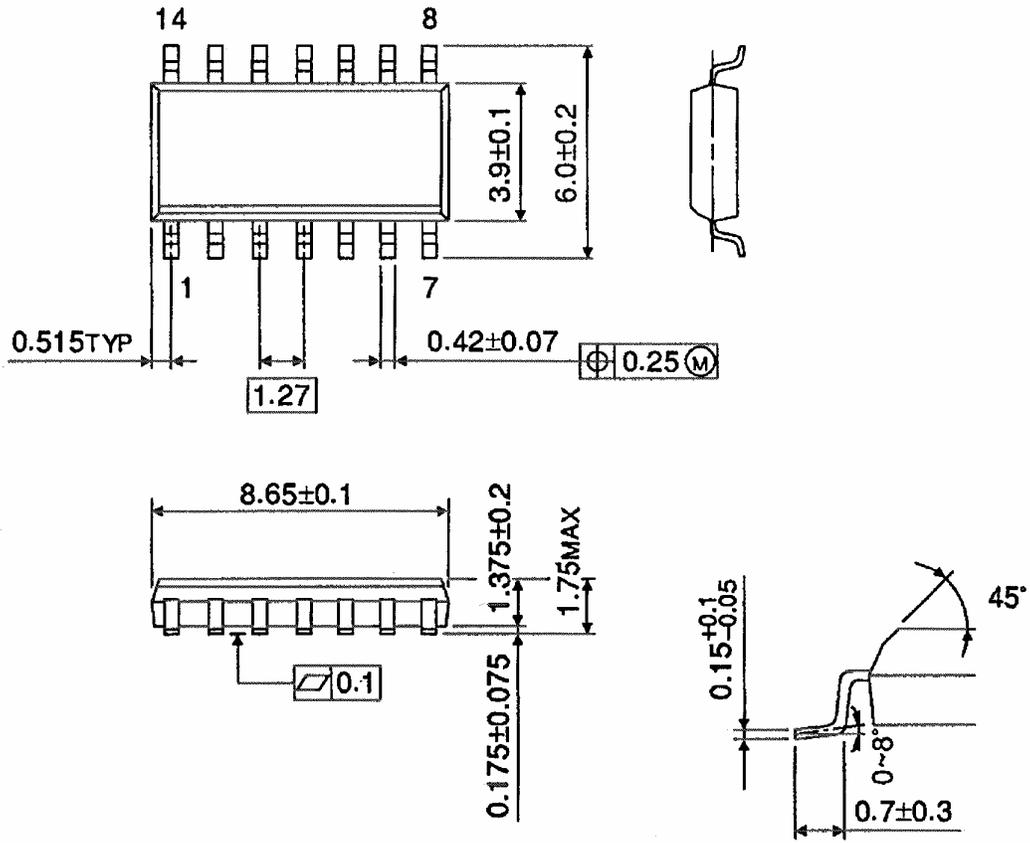


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

**Note: Lead (Pb)-Free Packages****DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27****RESTRICTIONS ON PRODUCT USE**

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